

Open-mode Design Capacitors

■ HOW TO ORDER

ОР	32	В	103	K	201	С	Т
<u>Series</u>	<u>Size</u>	<u>Dielectric</u>	<u>Capacitance</u>	<u>Tolerance</u>	Rated voltage	<u>Termination</u>	<u>Packaging</u>
OP=Open-mode	21=0805 (2012) 31=1206 (3216) 32=1210 (3225) 43=1812 (4532)	B=X7R	Two significant digits followed by no. of zeros. And R is in place of decimal point. eg.: 102=10x10² =1000pF	K=±10% M=±20%	Two significant digits followed by no. of zeros. And R is in place of decimal point. 101=100 VDC 201=200 VDC 251=250 VDC 501=500 VDC	L=Ag/Ni/Sn C=Cu/Ni/Sn (Note 1)	B=Bulk T=7" reeled G=13" reeled

Note 1: Please see below product range table to find right termination code.

■ PACKAGING DIMENSION AND QUANTITY

Ci	This law a see (1999) (2999)		Paper	r tape	Plastic tape		
Size	Thickness (mm)/Sym	DOI	7" reel	13" reel	7" reel	13" reel	
0005	0.80±0.10	В	4k	15k	-	-	
0805	1.25±0.10	D	-	-	3k	10k	
	0.80±0.10	В	4k	15k	-	-	
1007	0.95±0.10	С	-	-	3k	10k	
1206	1.25±0.10	D	-	-	3k	10k	
	1.60±0.20	G	-	-	2k	-	
	0.95±0.10	С	-	-	3k	10k	
4040	1.25±0.10	D	-	-	3k	10k	
1210	1.60±0.20	G	-	-	2k	-	
	2.50±0.30	М	-	-	1k	-	
4040	1.25±0.10	D	-	-	1k	-	
1812	2.00±0.20	K	-	-	1k	-	

Unit: pieces

■ INNER CONSTRUCTION OF OPEN-MODE DESIGN

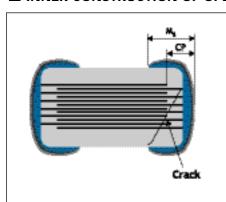


Fig. 2 Normal design (CP<M_B) – circuit leakage during cracking.

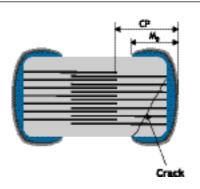


Fig. 3 Open-mode design (CP>MB) – circuit open during cracking.

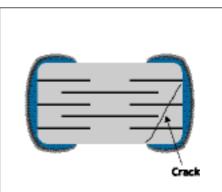


Fig. 4 Floating design (one kind of open-mode design) – circuit open during cracking.



Open-mode Design Capacitors

■ CAPACITANCE RANGE

	Dielectric	X7R															
	Size		80	05			12	06			1:	210			18	312	
Rat	ed Voltage (VDC)	100	200	250	500	100	200	250	500	100	200	250	500	100	200	250	500
	100pF (101)	В	В	В	В^												
	120pF (121)	В	В	В	В^												
	150pF (151)	В	В	В	В^	В	В	В	B^								
	180pF (181)	В	В	В	В^	В	В	В	B^								
	220pF (221)	В	В	В	B^	В	В	В	B^								
	270pF (271)	В	В	В	B^	В	В	В	B^								
	330pF (331)	В	В	В	B^	В	В	В	B^								
	390pF (391)	В	В	В	B^	В	В	В	B^								
	470pF (471)	В	В	В	B^	В	В	В	B^								
	560pF (561)	В	В	В	B^	В	В	В	B^								
	680pF (681)	В	В	В	B^	В	В	В	B^								
	820pF (821)	В	В	В	B^	В	В	В	B^								
	1,000pF (102)	В	В	В	В^	В	В	В	В^	С	С	С	C^	D	D	D	D^
	1,200pF (122)	В	В	В	В^	В	В	В	В^	С	С	С	C^	D	D	D	D^
	1,500pF (152)	В	В	В	В^	В	В	В	В^	С	С	С	C^	D	D	D	D^
	1,800pF (182)	В	В	В	В^	В	В	В	В^	С	С	С	C^	D	D	D	D^
	2,200pF (222)	В	В	В	В^	В	В	В	В^	С	С	С	C^	D	D	D	D^
	2,700pF (272)	В	В	В	В^	В	В	В	В^	С	С	С	C^	D	D	D	D^
	3,300pF (332)	В	В	В		В	В	В	В^	С	С	С	C^	D	D	D	D^
	3,900pF (392)	В	В	В		В	В	В	В^	С	С	С	C^	D	D	D	D^
	4,700pF (472)	В	В	В		В	В	В	В^	С	С	С	C^	D	D	D	D^
<u>g</u>	5,600pF (562)	В	D	D		В	В	В	B^	С	С	С	C^	D	D	D	D^
citar	6,800pF (682)	В	D	D		В	В	В	B^	С	С	С	C^	D	D	D	D^
Capacitance	8,200pF (822)	В	D	D		В	В	В	C^	С	С	С	C^	D	D	D	D^
Ü	0.010µF (103)	В	D	D		В	В	В	C^	С	С	С	C^	D	D	D	D^
	0.012µF (123)	В	D	D		В	В	В	D^	С	С	С	C^	D	D	D	D^
	0.015µF (153)	В	D	D		В	С	С	D^	С	С	С	C^	D	D	D	D^
	0.018µF (183)	В	D	D		В	С	С	D^	С	С	С	C^	D	D	D	D^
	0.022µF (223)	В	D	D		В	С	С	G^	С	С	С	D^	D	D	D	D^
	0.027µF (273)	D				В	С	С	G^	С	С	С	G^	D	D	D	D^
	0.033µF (333)	D				В	G	G	G^	С	С	С	G^	D	D	D	D^
	0.039µF (393)	D				В	G	G		С	С	С	G^	D	D	D	D^
	0.047µF (473)	D				В	G	G		С	D	D	G^	D	D	D	D^
	0.056µF (563)					В	G	G		С	D	D	G^	D	D	D	Κ^
	0.068µF (683)					В	G	G		С	G	G		D	D	D	Κ^
	0.082µF (823)					В	G	G		С	G	G		D	D	D	Κ^
	0.10µF (104)					D	G	G		С	G	G		D	D	D	Κ^
	0.12µF (124)					D				С	G	G		D	D	D	
	0.15µF (154)					G				D	М	М		D	K	K	
	0.18µF (184)					G				D	М	М		D	K	K	
	0.22µF (224)					G				D	М	М		D	K	K	
	0.27µF (274)									G				D	K	K	
	0.33µF (334)									G				D	K	K	
	0.39µF (394)									М				D	K	K	
	0.47µF (474)									М				K	K	K	
	0.56µF (564)									М				K			
	0.68µF (684)													K			
	0.82µF (824)													K			
	1.0µF (105)													K			

- The letter in cell is expressed the symbol of product thickness.
 The letter in cell with "^" mark is expressed product with Ag/Ni/Sn terminations.
- 3. For more information about products with special capacitance or other data, please contact WTC local representative.



Appendix I: Reliability Test Conditions and Requirements

NO.	Item	Test Condition	Requirements							
1.	Visual and Mechanical		No remarkable defect. Dimensions to confirm to individual specification sheet.							
2.	Capacitance	Class I : NPO	* Shall not exceed the limits given in the detailed spec.							
3.	Q/ D.F. (Dissipation Factor)	Cap 1000pF 1.0±0.2Vrms, 1MHz±10% NPO: Cap 30pF, Q 1000; Cap<30pF, Q 400+20C								
	(Dissipation Factor)	OLAND VED VED	Rated vol. D.F. Exception of D.F.							
		Class II : X7R, X5R, Y5V Cap 10µF, 1.0±0.2Vrms, 1KHz±10%	50V 2.5% 3.0% All 0201;0603 0.047μF;0805 0.18μF;							
		Cap>10μF, 0.5±0.2Vrms, 120Hz±20%	25V 3.5% 5.0% 0805 1µF, 1210 10µF							
			7.0% 0603 0.33µF;TT series & Cap 1µF							
			16V 3.5% 0805 0.68μF;1206 2.2μF							
			10% TT series & Cap 1μF 10V 5.0% 10.0% TT series & Cap 1μF:0805 10μF							
			6.3V 10.0% 15.0% 0805 22μF;1210 100μF							
			Y5V:							
			Rated vol. D.F. Exception of D.F. 50V 5.0%							
			35V 7.0%							
			7.0% 0603 0.1µF; 0805 0.33µF;							
			25V 5.0% 7.0% 1206 1μF; 1210 4.7μF 9.0% 0402 0.068μF							
			16V (C<1.0μF) 7.0% 9.0% 0402 0.068μF; 0603 0.68μF							
			16V (C 1.0μF) 9.0% 12.5% 0805 4.7μF;1206 10μF;1210 22μF							
			10V 12.5% 6.3V 20.0%							
			0.37 20.070							
4a.	Dielectric Strength	* To apply voltage (50V) 250%.	* No evidence of damage or flash over during test.							
		* Duration: 1 to 5 sec. * Charge & discharge current less than 50mA.								
	•	* To apply voltage :								
		100V 3 times V DC								
		200V ~ 300V 2 times V DC 500V ~ 999V 1.5 times V DC								
		1000V ~ 3000V 1.2 times V DC								
		* Cut-off, set at 10mA								
		* TEST= 15 sec. * RAMP=0								
4b.	Dielectric Strength (for X1/Y2 & X2/Y3)	* To apply 1500 VAC voltage. * Duration: 60 sec.	* No evidence of damage or flash over during test.							
5.	Insulation Resistance	To apply rated voltage for max. 120 sec.	10G or RxC 500 -F whichever is smaller.							
		Rated voltage: 100 ~ 500V To apply rated voltage for 60 sec.	10G							
		Rated voltage: To apply 500V for 60 sec.	10G							
		> 500V								
6.	Temperature	With no electrical load.								
	Coefficient	T.C. Operating Temp	T.C. Capacitance Change							
		NP0 (C0G) -55~125°C at 25°C NP0 (C0J) -55~125°C at 25°C	NP0 (COG) Within ±30ppm/°C NP0 (COJ) Within ±120ppm/°C							
		X7R -55~125°C at 25°C	X7R Within ±15%							
		X5R -55~85°C at 25°C	X5R Within ±15%							
		Y5V -25~85°C at 20°C	Y5V Within +30%/-80%							
7.	Adhesive Strength	* Pressurizing force:	* No remarkable damage or removal of the terminations.							
	of Termination	0201: 2N								
		0402 & 0603: 5N >0603: 10N								
		* Test time: 10±1 sec.								
8.	Vibration	* Vibration frequency: 10~55 Hz/min.	* No remarkable damage.							
	Resistance	* Cap change and Q/D.F.: To meet initial spec.								
		* Test time: 6 hrs. (Two hrs each in three								
		mutually perpendicular directions.)								



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NO.	Item	Test Condition	Requirements						
9.	Solderability	* Solder temperature: 235±5°C * Dipping time: 2±0.5 sec.	95% min. coverage of all metalized area.						
10.	Bending Test	* The middle part of substrate shall be pressurized by means of the pressurizing rod at a rate of about 1 mm per second until the deflection becomes 1 mm and then the pressure shall be maintained for 5±1 sec. * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change: NP0: within ±5.0% or ±0.5pF whichever is larger. X7R, X5R: within ±12.5% Y5V: within ±30% (This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)						
11.	Resistance to Soldering Heat	* Solder temperature: 270±5°C * Dipping time: 10±1 sec * Preheating: 120 to 150°C for 1 minute before immerse the capacitor in an eutectic solder. * Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 48±4 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs. (Class I) or 48±4 hrs. (Class II).	* No remarkable damage. * Cap change: NP0: within ±2.5% or ±0.25pF whichever is larger. X7R, X5R: within ±7.5% Y5V: within ±20% * O/D.F., I.R. and dielectric strength: To meet initial requirements. * 25% max. leaching on each edge.						
12.	Temperature Cycle	* Conduct the five cycles according to the temperatures and time. Step Temp. (°C) Time (min.) 1 Min. operating temp. +0/-3 30±3 2 Room temp. 2~3 3 Max. operating temp. +3/-0 30±3 4 Room temp. 2~3 * Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 48±4 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs. (Class I) or 48±4 hrs. (Class II).	* No remarkable damage. * Cap change: NPO: within ±2.5% or ±0.25pF whichever is larger. X7R, X5R: within ±7.5% Y5V: within ±20% * Q/D.F., I.R. and dielectric strength: To meet initial requirements.						
13.	Humidity (Steady State)	* Test temp.: 40±2°C * Humidity: 90~95% RH * Test time: 500+24/-0hrs. * Measurement to be made after keeping at room temp. for 24±2 hrs. (Class I) or 48±4 hrs. (Class II).	* No remarkable damage. * Cap change: NPO: within ±5.0% or ±0.5pF whichever is larger. X7R, X5R: 10V, within ±12.5% 6.3V, within ±25% Y5V: within ±30% * Q/D.F. value: NPO: Cap 30pF, Q 350; 10pF Cap<30pF, Q 275+2.5C Cap<10pF; Q 200+10C X7R, X5R: Rated vol. D.E. Exception of D.F. 50V 3.0% 6.0% 0603 0.047µF; 0805 0.18µF; 1206 0.47µF 25V 5.0% 10.0% 0805 1µF, 1210 10µF 14.0% 0603 0.33µF 16V 5.0% 10.0% 0402 0.033µF; 0603 0.15µF; 0805 0.68µF; 1206 2.2µF 10V 7.5% 15.0% 0805 2.2µF; 1206 2.2µF, TT series & Cap 1µF 6.3V 15.0% 30.0% 0805 10µF; 1210 100µF Y5V: Rated vol. D.F. Exception of D.F. 50V 7.5% 35V 10.0% 25V 7.5% 10.0% 0603 0.1µF; 0805 0.33µF; 1206 1µF; 1210 4.7µF 12.5% 0402 0.068µF 16V (C<1.0µF) 10.0% 12.5% 0402 0.068µF 16V (C 1.0µF) 12.5% 10V 15.0% 10V						



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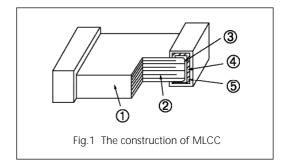
NO.	Item	Test Condition	Requirements					
14.	Humidity Load (Damp Heat)	* Test temp.: 40±2°C * Humidity: 90~95%RH * Test time: 500+24/-0 hrs. * To apply voltage: rated voltage (Max. 500V) * Measurement to be made after keeping at room temp. for 24±2 hrs. (Class I) or 48±4 hrs. (Class II).	* No remarkable damage. * Cap change: NPO: within ±7.5% or ±0.75pF whichever is larger. X7R, X5R: 10V, within ±12.5% 6.3V, with ±25% Y5V: 10V, within ±30% 6.3V, within +30 to -40% * Q/D.F. value: NPO: Cap 30pF, Q 200; Cap<30pF, Q 100+10/3C					
			X7R, X5R: Rated vol. D.F. Exception of D.F.					
			Rated vol. D.F. Exception of D.F. 50V 7.5%					
15.	High Temperature Load (Endurance)	* Test temp.: NPO, X7R: 125±3°C X5R, Y5V: 85±3°C * To apply voltage: (1) 6.3V or C 10µF (for X7R, X5R): 150% of rated voltage. (2) 6.3V <v<500v (3)="" (4)="" (class="" (for="" (max.="" *="" -0="" 1000+24="" 120%="" 150%="" 200%="" 24±2="" 3600v)="" 48±4="" 500v:="" 630v:="" after="" and="" at="" be="" c<10µf="" for="" hrs.="" i)="" ii).<="" keeping="" made="" measurement="" of="" or="" rated="" room="" temp.="" test="" th="" time:="" to="" v="" voltage.="" x5r):="" x7r,=""><th>* No remarkable damage. * Cap change: NPO: within ±3.0% or ±0.3pF whichever is larger. X7R, X5R: 10V, within ±12.5% 6.3V, with ±25% Y5V: 10V, within ±30% 6.3V, within ±30 to -40% * Q/D.F. value: NPO: Cap 30pF, Q 350 10pF Cap<30pF, Q 275+2.5C Cap<10pF, Q 200+10C X7R, X5R: Rated vol. D.F. Exception of D.F. 50V 3.0% 6.0% 0603 0.047µF; 0805 0.18µF, 1206 0.47µF 25V 5.0% 10.0% 0805 1µF, 1210 10µF 14.0% 0603 0.33µF 16V 5.0% 10.0% 0805 0.68µF; 1206 2.2µF 10V 7.5% 15.0% 0805 2.2µF; 1206 2.2µF TT series & Cap 1µF</th></v<500v>	* No remarkable damage. * Cap change: NPO: within ±3.0% or ±0.3pF whichever is larger. X7R, X5R: 10V, within ±12.5% 6.3V, with ±25% Y5V: 10V, within ±30% 6.3V, within ±30 to -40% * Q/D.F. value: NPO: Cap 30pF, Q 350 10pF Cap<30pF, Q 275+2.5C Cap<10pF, Q 200+10C X7R, X5R: Rated vol. D.F. Exception of D.F. 50V 3.0% 6.0% 0603 0.047µF; 0805 0.18µF, 1206 0.47µF 25V 5.0% 10.0% 0805 1µF, 1210 10µF 14.0% 0603 0.33µF 16V 5.0% 10.0% 0805 0.68µF; 1206 2.2µF 10V 7.5% 15.0% 0805 2.2µF; 1206 2.2µF TT series & Cap 1µF					
			11 Series & Cap TµF					



Appendix II: General Information

Constructions

No.	Na	me	NPO/X7R	X7R/X5R/Y5V		
1	Ceramic	material	BaTiO₃ based			
2	Inner el	ectrode	AgPd alloy	Ni		
3		Inner layer		Cu		
4	Termination	Middle layer	Ni Ni			
5		Outer layer	Sn (N	Matt)		



Storage and handling conditions

- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

- a. Don't store products in a corrosive environment such as sulfide, chloride gas, or acid. It may cause oxidization of electrode, which easily be resulted in poor soldering.
- b. To store products on the shelf and avoid exposure to moisture.
- c. Don't expose products to excessive shock, vibration, direct sunlight and so on.

Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N₂ within oven are recommended.

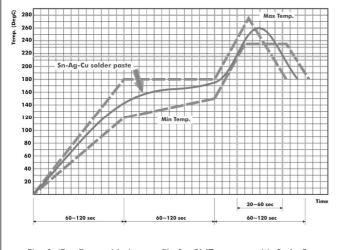


Fig. 2 IR reflow soldering profile for SMT process with SnAgCu series solder paste.

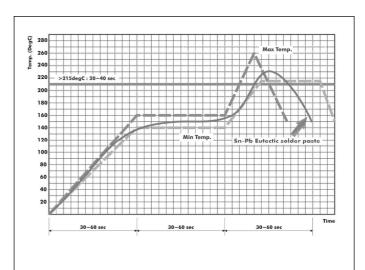


Fig. 3 IR reflow soldering profile for SMT process with eutectic SnPb solder paste.